

REMARKS


Claims 24-33 are pending in the present application. Claims 1-23 were previously cancelled. Claims 24 and 27 have been amended herein. No new matter has been added.

Claims 24-33 have been rejected under 35 U.S.C. § 102(b) as assertedly being anticipated by U.S. Patent No. 5,674,770 to Lee et al. (hereinafter "Lee"). In particular, the Office Action asserted that the word "on" means "in close proximity," and suggests that Applicants mean "in contact with." Accordingly, Applicants have amended independent claim 24 to recite "forming a second polysilicon layer, the second polysilicon layer being in contact with the logic gate oxide in the periphery region and in contact with the first doped polysilicon layer in the cell region," as suggested by the Examiner.

In view of the above, Applicants respectfully submit that this response complies with 37 C.F.R. § 1.116. Applicants further submit that the claims are in condition for allowance. No new matter has been added by this amendment. If the Examiner should have any questions, please contact Applicants' attorney at the number listed below. No fee is believed due in connection with this filing. However, in the event that there are any fees due, please charge the same, or credit any overpayment, to Deposit Account No. 50-1065.

Respectfully submitted,

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Date


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